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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/749,921	12/29/2000	Robert J. O'Donnell	015290-465	6804
21839	7590 04:14/2005		EXAMINER	
BURNS DOANE SWECKER & MATHIS L L P			TRAN, BINH X	
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DATE MAILED: 04/14/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

			<u> </u>
		Application No.	Applicant(s)
Office Action Summary		09/749,921	O'DONNELL ET AL.
		Examiner	Art Unit
		Binh X. Tran	1765
Period f	The MAILING DATE of this communication app or Reply	pears on the cover sheet with the	correspondence address
THE - Extended - If th - If No - Fail Any	HORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. ensions of time may be available under the provisions of 37 CFR 1.13 or SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a reply operiod for reply is specified above, the maximum statutory period or ure to reply within the set or extended period for reply will, by statute the reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be to ywithin the statutory minimum of thirty (30) dawill apply and will expire SIX (6) MONTHS from the application to become ABANDON	timely filed  ays will be considered timely.  m the mailing date of this communication.  IED (35 U.S.C. § 133).
Status			
1)⊠ 2a)□ 3)□	This action is <b>FINAL</b> . 2b)⊠ This	s action is non-final. nce except for formal matters, p	
Disposit	tion of Claims		
5)⊠ 6)⊠ 7)□	Claim(s) 8,10-18 and 24-33 is/are pending in the same claim(s) is/are withdraw Claim(s) 25 and 29 is/are allowed.  Claim(s) 8,10-18,24,26-28 and 30-33 is/are rejuding(s) is/are objected to.  Claim(s) are subject to restriction and/or	wn from consideration.	
Applicat	tion Papers		
10)⊠	The specification is objected to by the Examine The drawing(s) filed on <u>23 January 2002</u> is/are: Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	: a)⊠ accepted or b)⊡ objecte drawing(s) be held in abeyance. So tion is required if the drawing(s) is o	ee 37 CFR 1.85(a). bjected to. See 37 CFR 1.121(d).
Priority	under 35 U.S.C. § 119		
a)	Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority documents  2. Certified copies of the priority documents  3. Copies of the certified copies of the priority application from the International Bureau  See the attached detailed Office action for a list	s have been received. s have been received in Applica rity documents have been receiv u (PCT Rule 17.2(a)).	ition No ved in this National Stage
Attachmer			
2)	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) rmation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date	4)  Interview Summar Paper No(s)/Mail [ 5)  Notice of Informal 6)  Other:	

Application/Control Number: 09/749,921 Page 2

Art Unit: 1765

#### **DETAILED ACTION**

#### Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 1-24-2005 has been entered.

### Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

4. Claims 8, 10, 13-18, 24, 26, 30, 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shamouilian et al. (US 5,606,485) in view of Clarke et al. (US 6,120,854).

Page 3

Respect to claim 8, Shamouilian ('485) discloses a component (20) of semiconductor processing equipment, the component (20) comprising a substrate (28) having a surface and a polymer coating (22: 22a and/or 22b) on the surface of the substrate (28) and forming an outer surface of the component, the outer surface being resistant to plasma erosion and corrosion, wherein the component (20) is component other than a chamber liner (See col. 4 lines 23-67, col. 7 lines 10-20, Fig 1-3).

Shamouilian ('485) fails to disclose that the polymer material is liquid crystal polymer. Clarke discloses that liquid crystal polymer has superior property including extremely high flow, significant melt strength than regular polymer (col. 2 lines 35-45). It would have been obvious to one having ordinary skill in the art, at the time of invention, to modify Shamouilian ('485) in view of Clarke by using liquid crystal polymer because it is capable of withstanding high temperature due to significant melt strength property.

Respect to independent claim 13, Shamouilian fails to disclose the polymer is plasma sprayed liquid crystal polymer. However, Shamouilian ('485) clearly teaches to spray polymer material on the substrate (col. 7 lines 29-34). Clarke teaches to use plasma sprayed liquid crystal polymer because this technique is capable of forming a uniform surface (col. 4 lines 55-67). It would have been obvious to one having ordinary skill in the art, at the time of invention, to modify Shamouilian ('485) in view of Clarke by

Art Unit: 1765

using plasma sprayed liquid crystal polymer because this technique is capable of forming a uniform surface.

Respect to claim 10, Clarke disclose the substrate (28) comprises aluminum (col. 6 lines 50-52). Respect to claims 14, 24 and 33, Shamouilian ('485) discloses the component (20) is an electrostatic chuck. Respect to claim 15, Shamouilian ('485) discloses the polymer (22a and/or 22b) comprises a preformed sheet cover the surface of the substrate (28) (Fig 1). The liquid crystalline polymer limitation in claim 15 has been discussed above under Clarke's reference.

Respect to claim 16, Shamouilian ('485) discloses the component comprise a roughen surface that has been subjected to a surface roughen treatment and is in contact with the polymer applied on the surface (col. 6 lines 50-64). Respect to claim 17, Shamouilian ('485) discloses the polymer material (22) includes a filler (col. 5 lines 33-41). The liquid crystalline polymer limitation in claim 17 has been discussed above under Clarke's reference.

Respect to claim 18, Shamouilian ('485) discloses a plasma chamber (40) comprise at least one component (20). Respect to claims 26 and 30, Shamouilian ('485) discloses at least intermediate layer (22b or 24) between the surface of the substrate (28) and the coating (22a).

5a. Claims 11, 27-28 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shamouilian ('485) in view of Clarke as applied to claim 8 above, and further in view of Shamouilian (US 2002/0036881).

Application/Control Number: 09/749,921

Art Unit: 1765

5b. Claims 31-32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shamouilian ('485) in view of Clarke as applied to claim 8 above, and further in view of Shamouilian (US 2002/0036881).

Respect to claims 11, 27-28, 31-32 Shamouilian ('485) fails to disclose that the substrate comprises alumina (claim 11), or refractory metal (claims 27, 31) or ceramic material selected from the group consisting of silicon carbide, silicon nitride, boron carbide, and boron nitride (claims 28, 32). However, Shamouilian ('485) clearly discloses the base of the chuck (i.e. the substrate) comprise aluminum (col. 6 lines 51-56). In a semiconductor apparatus, Shamouilian ('881) discloses the chuck have a base comprises either aluminum, or aluminum oxide (aka alumina), refractory metal (i.e. titanium, tungsten), or ceramic material selected from the group consisting of silicon carbide, silicon nitride, boron carbide, and boron nitride (page 3 paragraphs 0037). It would have been obvious to one having ordinary skill in the art, at the time of invention, to modify Shamouilian ('485) and Clarke in view of Shamouilian ('881) by using alumina, refractory metal or ceramic material selected from the group consisting of silicon carbide, silicon nitride, boron carbide, and boron nitride because equivalent and substitution of one for the other would produce an expected result.

6. Claim 12 is rejected under 35 U.S.C. 103(a) as being unpatentable over Shamouilian (US 5,606,485) in view of Clarke as applied to claim 10 above, and further in view of Whitlock et al. (US 4,736,087).

Respect to claim 12, Shamouilian fails to disclose the component includes an anodized surface. However, Shamouilian clearly discloses the component is a chuck

Art Unit: 1765

comprises aluminum. In a semiconductor apparatus, Whitlock teaches to use either aluminum or anodized aluminum for the chuck (col. 3 lines 68 to col. 4 line 3). It would have been obvious to one having ordinary skill in the art, at the time of invention, to modify Shamouilian ('485) and Clarke in view of Whitlock by using anodized aluminum because equivalent and substitution of one for the other would produce an expected result.

## Allowable Subject Matter

- 7. Claims 25, 29 are allowed.
- 8. The following is a statement of reasons for the indication of allowable subject matter: The reason for allowance was discussed in previous office action.

### Response to Arguments

9. Applicant's arguments with respect to claims 8, 10-18, 24, 26-28, 30-33 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Binh X. Tran whose telephone number is (571) 272-1469. The examiner can normally be reached on Monday-Thursday and every other Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on (571) 272-1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 09/749,921 Page 7

Art Unit: 1765

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

BinhTran

Binh X. Tran